1Mx36 & 2Mx18 QDR[™] II+ b4 SRAM

36Mb QDRII+ SRAM Specification

165 FBGA with Pb & Pb-Free (RoHS compliant)

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1Mx36 & 2Mx18 QDR[™] II+ b4 SRAM

Document Title

1Mx36-bit, 2Mx18-bit QDR™ II+ b4 SRAM

Revision History

| <u>Rev. No.</u> | History | Draft Date | <u>Remark</u> |
|-----------------|--|---------------|---------------|
| 0.0 | 1. Initial document. | Nov. 2, 2005 | Advance |
| 0.1 | 1. Change the DLL locking time - Before: 1024 cycle - After: 2048 cycle | Nov. 25, 2005 | Preliminary |
| 0.2 | 1. Add comment Pb Free and Industrial | Mar. 03, 2006 | Preliminary |
| 0.3 | 1. Change Max of clock cycle time | Mar. 03, 2006 | Preliminary |
| 0.4 | 1. Change DC Characteristics, Pin Capacitance and Thermal Resis- tance | Apr. 25 2006. | Preliminary |
| 0.5 | 1. Correct errors | May. 03 2006 | Preliminary |
| 0.6 | 1. Change Samsung JEDEC Code in ID REGISTER DEFINITION | Jun. 05, 2006 | Preliminary |
| 1.0 | 1. Correct typo | Aug. 21, 2006 | Final |
| 1.1 | Change programmable impedence output buffer operation Add AC Timing Characteristics | Jan. 30, 2007 | Final |
| 1.2 | 1. Add AC/DC parameter 450MHz | Mar. 16, 2007 | Final |
| 1.3 | 1. Delete AC/DC parameter 450MHz | Aug. 27, 2007 | Final |



1Mx36 & 2Mx18 QDR[™] II+ b4 SRAM

1Mx36-bit, 2Mx18-bit QDR™ II+ b4 SRAM

FEATURES

- 1.8V+0.1V/-0.1V Power Supply.
- DLL circuitry for wide output data valid window and future frequency scaling.
- I/O Supply Voltage 1.5V+0.1V/-0.1V
- Separate independent read and write data ports
 with concurrent read and write operation
- HSTL I/O
- Full data coherency, providing most current data .
- Synchronous pipeline read with self timed late write.
- Read latency: 2 clock cycles
- Registered address, control and data input/output.
- DDR(Double Data Rate) Interface on read and write ports.
- Fixed 4-bit burst for both read and write operation.
- Clock-stop supports to reduce current.
- Two input clocks(K and $\overline{\mathsf{K}})$ for accurate DDR timing at clock rising edges only.
- Two echo clocks (CQ and \overline{CQ}) to enhance output data traceability.
- Data Valid pin(QVLD) supported
- Single address bus.
- Byte write (x18, x36) function.
- Separate read/write control pin(\overline{R} and \overline{W})
- Simple depth expansion with no data contention.
- Programmable output impedance(ZQ).
- JTAG 1149.1 compatible test access port.
- 165FBGA(11x15 ball array) with body size of 15mmx17mm.

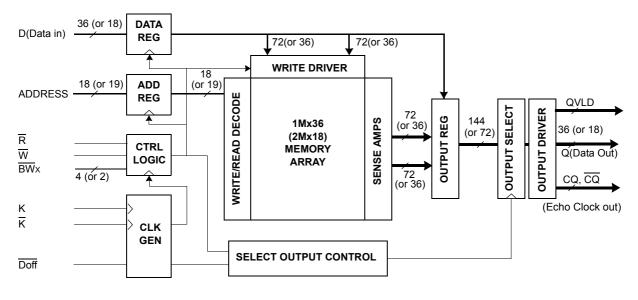
| Organiza- tion | Part Number | Cycle Time | Access Time | Unit |
|-------------------|-----------------------|---------------|----------------|------|
| | K7S3236T4C-F(E)C(I)45 | 2.22 | 0.45 | ns |
| X36 | K7S3236T4C-F(E)C(I)40 | 2.5 | 0.45 | ns |
| | K7S3236T4C-F(E)C(I)33 | 3.0 | 0.45 | ns |
| | K7S3236T4C-F(E)C(I)45 | 2.22 | 0.45 | ns |
| X18 | K7S3218T4C-F(E)C(I)40 | 2.5 | 0.45 | ns |
| | K7S3218T4C-F(E)C(I)33 | 3.0 | 0.45 | ns |

* -F(E)C(I)

F(E) [Package type] : E-Pb Free, F-Pb

C(I) [Operating Temperature] : C-Commercial, I-Industrial

FUNCTIONAL BLOCK DIAGRAM



Notes: 1. Numbers in () are for x18 device

QDR SRAM and Quad Data Rate comprise a new family of products developed by Cypress, Renesas, IDT, NEC and Samsung technology.



1Mx36 & 2Mx18 QDR[™] II+ b4 SRAM

| PIN C | ONFIGL | IRATION | IS (TOP V | IEW) K | 7S3236T4 | C (1Mx36 |) | | | | |
|-------|--------|---------|------------------|--------|----------|----------|-----------------|------|------|--------|-----|
| | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 10 | 11 |
| Α | CQ | NC/SA* | NC/SA* | W | BW2 | ĸ | BW ₁ | R | SA | NC/SA* | CQ |
| в | Q27 | Q18 | D18 | SA | BW3 | К | BW ₀ | SA | D17 | Q17 | Q8 |
| С | D27 | Q28 | D19 | Vss | SA | NC | SA | Vss | D16 | Q7 | D8 |
| D | D28 | D20 | Q19 | Vss | Vss | Vss | Vss | Vss | Q16 | D15 | D7 |
| Е | Q29 | D29 | Q20 | Vddq | Vss | Vss | Vss | Vddq | Q15 | D6 | Q6 |
| F | Q30 | Q21 | D21 | Vddq | Vdd | Vss | Vdd | Vddq | D14 | Q14 | Q5 |
| G | D30 | D22 | Q22 | Vddq | Vdd | Vss | Vdd | Vddq | Q13 | D13 | D5 |
| н | Doff | VREF | VDDQ | Vddq | Vdd | Vss | Vdd | Vddq | VDDQ | VREF | ZQ |
| J | D31 | Q31 | D23 | Vddq | Vdd | Vss | Vdd | Vddq | D12 | Q4 | D4 |
| к | Q32 | D32 | Q23 | Vddq | Vdd | Vss | Vdd | Vddq | Q12 | D3 | Q3 |
| L | Q33 | Q24 | D24 | Vddq | Vss | Vss | Vss | Vddq | D11 | Q11 | Q2 |
| м | D33 | Q34 | D25 | Vss | Vss | Vss | Vss | Vss | D10 | Q1 | D2 |
| Ν | D34 | D26 | Q25 | Vss | SA | SA | SA | Vss | Q10 | D9 | D1 |
| Р | Q35 | D35 | Q26 | SA | SA | QVLD | SA | SA | Q9 | D0 | Q0 |
| R | TDO | TCK | SA | SA | SA | NC | SA | SA | SA | TMS | TDI |

Notes: 1. * Checked No Connect(NC) pins are reserved for higher density address, i.e. 3A for 72Mb, 10A for 144Mb and 2A for 288Mb. 2. BW₀ controls write to D0:D8, BW₁ controls write to D9:D17, BW₂ controls write to D18:D26 and BW₃ controls write to D27:D35.

PIN NAME

| SYMBOL | PIN NUMBERS | DESCRIPTION | NOTE |
|--------------------|---|--|------|
| K, K | 6B, 6A | Input Clock | |
| QVLD | 6P | Q Valid output | |
| CQ, CQ | 11A, 1A | Output Echo Clock | |
| Doff | 1H | DLL Disable | |
| SA | 9A,4B,8B,5C,7C,5N-7N,4P,5P,7P,8P,3R-5R,7R-9R | Address Inputs | |
| D0-35 | 10P,11N,11M,10K,11J,11G,10E,11D,11C,10N,9M,9L 9J,10G,9F,10D,9C,9B,3B,3C,2D,3F,2G,3J,3L,3M,2N 1C,1D,2E,1G,1J,2K,1M,1N,2P | Data Inputs | |
| Q0-35 | 11P,10M,11L,11K,10J,11F,11E,10C,11B,9P,9N,10L 9K,9G,10F,9E,9D,10B,2B,3D,3E,2F,3G,3K,2L,3N 3P,1B,2C,1E,1F,2J,1K,1L,2M,1P | Data Outputs | |
| W | 4A | Write Control Pin,active when low | |
| R | 8A | Read Control Pin, active when low | |
| BW0, BW1, BW2, BW3 | 7B,7A,5A,5B | Block Write Control Pin, active when low | |
| VREF | 2H,10H | Input Reference Voltage | |
| ZQ | 11H | Output Driver Impedance Control Input | 1 |
| Vdd | 5F,7F,5G,7G,5H,7H,5J,7J,5K,7K | Power Supply (1.8 V) | |
| Vddq | 4E,8E,4F,8F,4G,8G,3H,4H,8H,9H,4J,8J,4K,8K,4L,8L | Output Power Supply (1.5V) | |
| Vss | 4C,8C,4D-8D,5E-7E,6F,6G,6H,6J,6K,5L-7L,4M,8M,4N,8N | Ground | |
| TMS | 10R | JTAG Test Mode Select | |
| TDI | 11R | JTAG Test Data Input | |
| TCK | 2R | JTAG Test Clock | |
| TDO | 1R | JTAG Test Data Output | |
| NC | 2A,3A,10A,6C,6R | No Connect | 2 |

Notes:

1. When ZQ pin is directly connected to Vob output impedance is set to minimum value and it cannot be connected to ground or left unconnected.

Not connected to chip pad internally.
 K, K can not be set to VREF voltage.



1Mx36 & 2Mx18 QDR[™] II+ b4 SRAM

PIN CONFIGURATIONS(TOP VIEW) K7S3218T4C (2Mx18)

| | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 10 | 11 | | |
|---|------|--------|------|------|-----|------|-------------|------|------|--------|-----|--|--|
| Α | CQ | NC/SA* | SA | W | BW1 | ĸ | NC | R | SA | NC/SA* | CQ | | |
| в | NC | Q9 | D9 | SA | NC | к | BW 0 | SA | NC | NC | Q8 | | |
| с | NC | NC | D10 | Vss | SA | NC | SA | Vss | NC | Q7 | D8 | | |
| D | NC | D11 | Q10 | Vss | Vss | Vss | Vss | Vss | NC | NC | D7 | | |
| Е | NC | NC | Q11 | Vddq | Vss | Vss | Vss | Vddq | NC | D6 | Q6 | | |
| F | NC | Q12 | D12 | Vddq | Vdd | Vss | Vdd | Vddq | NC | NC | Q5 | | |
| G | NC | D13 | Q13 | Vddq | Vdd | Vss | Vdd | Vddq | NC | NC | D5 | | |
| н | Doff | VREF | Vddq | Vddq | Vdd | Vss | Vdd | Vddq | Vddq | VREF | ZQ | | |
| J | NC | NC | D14 | Vddq | Vdd | Vss | Vdd | Vddq | NC | Q4 | D4 | | |
| к | NC | NC | Q14 | Vddq | Vdd | Vss | Vdd | Vddq | NC | D3 | Q3 | | |
| L | NC | Q15 | D15 | Vddq | Vss | Vss | Vss | Vddq | NC | NC | Q2 | | |
| М | NC | NC | D16 | Vss | Vss | Vss | Vss | Vss | NC | Q1 | D2 | | |
| N | NC | D17 | Q16 | Vss | SA | SA | SA | Vss | NC | NC | D1 | | |
| Р | NC | NC | Q17 | SA | SA | QVLD | SA | SA | NC | D0 | Q0 | | |
| R | TDO | ТСК | SA | SA | SA | NC | SA | SA | SA | TMS | TDI | | |

Notes: 1. <u>*</u> Checked No Connect(NC) pin<u>s</u> are reserved for higher density address, i.e. 10A for 72Mb and 2A for 144Mb. 2. BW₀ controls write to D0:D8 and BW₁ controls write to D9:D17.

PIN NAME

| SYMBOL | PIN NUMBERS | DESCRIPTION | NOTE |
|----------|--|--|------|
| К, К | 6B, 6A | Input Clock | |
| QVLD | 6P | Q Valid output | |
| CQ, CQ | 11A, 1A | Output Echo Clock | |
| Doff | 1H | DLL Disable | |
| SA | 3A,9A,4B,8B,5C,7C,5N-7N,4P,5P,7P,8P,3R-5R,7R-9R | Address Inputs | |
| D0-17 | 10P,11N,11M,10K,11J,11G,10E,11D,11C,3B,3C,2D 3F,2G,3J,3L,3M,2N | Data Inputs | |
| Q0-17 | 11P,10M,11L,11K,10J,11F,11E,10C,11B,2B,3D,3E 2F,3G,3K,2L,3N,3P | Data Outputs | |
| W | 4A | Write Control Pin, active when low | |
| R | 8A | Read Control Pin, active when low | |
| BW0, BW1 | 7B, 5A | Block Write Control Pin, active when low | |
| VREF | 2H,10H | Input Reference Voltage | |
| ZQ | 11H | Output Driver Impedance Control Input | 1 |
| Vdd | 5F,7F,5G,7G,5H,7H,5J,7J,5K,7K | Power Supply (1.8 V) | |
| Vddq | 4E,8E,4F,8F,4G,8G,3H,4H,8H,9H,4J,8J,4K,8K,4L,8L | Output Power Supply (1.5V) | |
| Vss | 4C,8C,4D-8D,5E-7E,6F,6G,6H,6J,6K,5L-7L,4M-8M,4N,8N | Ground | |
| TMS | 10R | JTAG Test Mode Select | |
| TDI | 11R | JTAG Test Data Input | |
| TCK | 2R | JTAG Test Clock | |
| TDO | 1R | JTAG Test Data Output | |
| NC | 2A,7A,10A,1B,5B,9B,10B,1C,2C,6C,9C,1D,9D,10D,1E,2E,9E,1F 9F,10F,1G,9G,10G,1J,2J,9J,1K,2K,9K,1L,9L,10L,1M 2M,9M,1N,9N,10N,1P,2P,9P,6R | No Connect | 2 |

Notes:

1. When ZQ pin is directly connected to VDD output impedance is set to minimum value and it cannot be connected to ground or left unconnected. Not connected to chip pad internally.
 K, K can not be set to VREF voltage.



1Mx36 & 2Mx18 QDR[™] II+ b4 SRAM

GENERAL DESCRIPTION

The K7S3236T4C and K7S3218T4C are37,748,736-bits QDR(Quad Data Rate) Synchronous Pipelined Burst SRAMs. They are organized as 1,048,576 words by 36bits for K7S3236T4C and 2,097,152 words by 18 bits for K7S3218T4C.

The QDR operation is possible by supporting DDR read and write operations through separate data output and input ports with the same cycle. Memory bandwidth is maximized as data can be transferred into and out of SRAM on every rising edge of K and \overline{K} . And totally independent read and write ports eliminate the need for high speed bus turn around.

Address for read and write are latched on alternate rising edges of the input clock K. Data inputs, data output, and all control signals are synchronized to the input clock (K or \overline{K}). Read data are referenced to echo clock (CQ or \overline{CQ}) outputs. Common address bus is used to access address both for read and write operations. The internal burst counter is fixed to 4-bit sequential for both read and write operations, requiring two full clock bus cycles. Any request that attempts to interrupt a burst operation in progress is ignored. Synchronous pipeline read and late write enable high speed operations. Simple depth expansion is accomplished by using \overline{R} and \overline{W} for port selection. Byte write operation is supported with \overline{BW}_0 and \overline{BW}_1 (\overline{BW}_2 and \overline{BW}_3) pins.

IEEE 1149.1 serial boundary scan (JTAG) simplifies monitoring package pads attachment status with system.

The K7S3236T4C and K7S3218T4C are implemented with SAMSUNG's high performance 6T CMOS technology and is available in 165pin FBGA packages. Multiple power and ground pins minimize ground bounce.

Read Operations

Read cycles are initiated by activating \overline{R} at the rising edge of the positive input clock K. Address is presented and stored in the read address register synchronized with K clock. For 4-bit burst DDR operation, it will access four 36-bit or 18-bit data words with each read command.

The first pipelined data is transferred out of the device triggered by K clock rising edge. Next burst data is triggered by the rising edge of following \overline{K} clock rising edge. The process continues until all four data are transferred. Continuous read operations are initiated with K clock rising edge. And pipelined data are transferred out of device on every rising edge of both K and \overline{K} clocks. Initial read data latency is 2 clock cycles when DLL is on.

When the \overline{R} is disabled after a read operation, the K7S3236T4C and K7S3218T4C will first complete burst read operation before entering into deselect mode at the next K clock rising edge. Then output drivers disabled automatically to high impedance state.

Write Operations

Write cycles are initiated by activating \overline{W} at the rising edge of the positive input clock K. Address is presented and stored in the write address register synchronized with K clock. For 4-bit burst DDR operation, it will write four 36-bit or 18-bit data words with each write command.

The first "late" data is transferred and registered in to the device synchronous with next K clock rising edge. Next burst data is transferred and registered synchronous with following \overline{K} clock rising edge. The process continues until all four data are transferred and registered. Continuous write operations are initiated with K rising edge. And "late writed" data is presented to the device on every rising edge of both K and \overline{K} clocks.

The device disregards input data presented on the same cycle \overline{W} disabled. When the \overline{W} is disabled after a write operation, the K7S3236T4C and K7S3218T4C will first complete burst write operation before entering into deselect mode at the next K clock rising edge.

The K7S3236T4C and K7S3218T4C support byte write operations. With activating $\overline{BW_0}$ or $\overline{BW_1}$ ($\overline{BW_2}$ or $\overline{BW_3}$) in write cycle, only one byte of input data is presented. In K7S3218T4C, $\overline{BW_0}$ controls write operation to D0:D8, $\overline{BW_1}$ controls write operation to D9:D17. And in K7S3236T4C, $\overline{BW_2}$ controls write operation to D18:D26, $\overline{BW_3}$ controls write operation to D27:D35.



1Mx36 & 2Mx18 QDR[™] II+ b4 SRAM

Depth Expansion

Separate input and output ports enables easy depth expansion. Each port can be selected and deselected independently and read and write operation do not affect each other. Before chip deselected, all read and write pending operations are completed.

Programmable Impedance Output Buffer Operation

The designer can program the SRAM's output buffer impedance by terminating the ZQ pin to Vss through a precision resistor(RQ). The allowable range of RQ is between 175Ω and 350Ω The value of RQ (within 15% tolerance) is five times the output impedance desired. For example, 250Ω resistor will give an output impedance of 50Ω .

Impedance updates occur early in cycles that do not activate the outputs, such as deselect cycles. In all cases impedance updates are transparent to the user and do not produce access time "push-outs" or other anomalous behavior in the SRAM. To guarantee optimum output driver impedance after power up, the SRAM needs 1024 non-read cycles.

Output Valid Pin (QVLD)

The Q Valid indicates valid output data. QVLD is activated half cycle before the read data for the receiver to be ready for capturing the data. QVLD is edge aligned with CQ and \overline{CQ} .

Echo clock operation

To assure the output traceability, the SRAM provides the output Echo clock, pair of compliment clock CQ and \overline{CQ} , which are synchronized with internal data output. Echo clocks run free during normal operation. The Echo clock is triggered by internal output clock signal, and transferred to external through same structures as output driver.

Power-Up/Power-Down Supply Voltage Sequencing

The following power-up supply voltage application is recommended: Vss, VDD, VDDQ, VREF, then VIN. VDD and VDDQ can be applied simultaneously, as long as VDDQ does not exceed VDD by more than 0.5V during power-up. The following power-down supply voltage removal sequence is recommended: VIN, VREF, VDDQ, VDD, VSs. VDD and VDDQ can be removed simultaneously, as long as VDDQ does not exceed VDD by more than 0.5V during power-down.



1Mx36 & 2Mx18 QDR[™] II+ b4 SRAM

Detail Specification of Power-Up Sequence in QDRII+ SRAM

QDRII+ SRAMs must be powered up and initialized in a predefined manner to prevent undefined operations.

Power-Up Sequence

- 1. Apply power and keep Doff at low state (All other inputs may be undefined)
 - Apply VDD before VDDQ
- Apply VDDQ before VREF or the same time with VREF
- 2. Just after the stable power and $clock(K,\overline{K})$, take \overline{Doff} to be high.
- 3. The additional 2048 cycles of clock input is required to lock the DLL after enabling DLL

* **Notes**: If you want to tie up the Doff pin to High with unstable clock, then you must stop the clock for a few seconds (Min. 30ns) to reset the DLL after it become a stable clock status.

DLL Constraints

- 1. DLL uses either K clock as its synchronizing input, the input should have low phase jitter which is specified as TK var.
- 2. The lower end of the frequency at which the DLL can operate is 120MHz.
- 3. If the incoming clock is unstable and the DLL is enabled, then the DLL may lock onto a wrong frequency and this may cause the failure in the initial stage.

| K, K | | havaar <mark>s</mark> tet | | | 2048 c | | | | |
|-----------------|----------|---------------------------|---|-------------------------|----------------|---------|-----|-----------|----------------|
| Status | Power-Up | Unstable CLKstage | | | Nucking | g Range | + + | | Any Command |
| | | | | Inputs CI must be si | | | | | |
| V_{DD} | | | l | | | | | | |
| V_{DDQ} | | 1 | | | | | | | |
| V_{REF} | / | | | / | | | | | |
| Doff | | | / | / | , , | | | | |

Power up & Initialization Sequence (Doff pin controlled)

Power up & Initialization Sequence (Doff pin Fixed high, Clock controlled)

| K, K | | | NŲ. | XA | u | | M | | N | י [| | \[\ u \] | | | <u>الالا</u> | | Ķ. | Ķ. | χ Υ |
|------------------|----------|----------|-----|--------|---------------|---|---------------|-----|------------|-------------|-------|-----------------|-----------|-----------|--------------|-----------|------------|------------|-------------|
| | | ا برا | 1 | 2 | | | | | Min 3 | 0ns | | 1 | 2048 | cycle | | _ | | | |
| Status | Power-Up | Ň | | Unsta | able stage | | \rightarrow | Sto | w p Clo | ick | | DL | L Locl | king R | ange | \sum | Any Cor | , mmanç | |
| | | 1 | 1 | 1 | 1 | 1 | 1 | | | 1 | | uts Clo | | I | 1 | I | I | 1 | 1 |
| V_{DD} | / | l I | 1 | l I | | | I | | | | i mus | t be st | able | | l I | | ı I | l l | |
| V _{DDQ} | | | | | | | | | | | | | | | | | | t | † _ |
| V_{REF} | | | | | 1 | | 1 | | | | 1 | | | | 1 | | | 1 | |

* Notes: When the operating frequency is changed, DLL reset should be required again. After DLL reset again, the minimum 2048 cycles of clock input is needed to lock the DLL.



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TRUTH TABLES

SYNCHRONOUS TRUTH TABLE

| к | R | w | | D | | | Q | | | | | |
|------------|----------------|-------|------------------|------------------|------------------|--------------------------|-------------------|-------------------------------|-------------------|-------------------------------|--------------|--|
| n n | ĸ | ** | D(A1) | D(A2) | D(A3) | D(A4) | Q(A1) | Q(A2) | Q(A3) | Q(A4) | OPERATION | |
| Stopped | х | х | Previous state | Previous state | Previous state | Previous state | Previous state | Previous state | Previous state | Previous state | Clock Stop | |
| \uparrow | Н | Н | Х | Х | Х | Х | High-Z | High-Z | High-Z | High-Z | No Operation | |
| ↑ | L^4 | х | х | х | х | х | Qout at K(t+2) | Q _{OUT} at K(t+2) | Qout at K(t+3) | Q _{OUT} at K(t+3) | Read | |
| 1 | H ⁵ | L^4 | Din at K(t+1) | Din at K(t+1) | Din at K(t+2) | <u>D</u> in at K(t+2) | х | х | х | х | Write | |

Notes: 1. X means "Don't Care".

2. The rising edge of clock is symbolized by (\uparrow).

3. Before enter into clock stop status, all pending read and write operations will be completed.

4. This signal was HIGH on previous K clock rising edge. Initiating consecutive READ or WRITE operations on consecutive K clock rising edges is not permitted. The device will ignore the second request.

5. If this signal was LOW to initiate the previous cycle, this signal becomes a don't care for this operation however it is strongly recommended that this signal is brought HIGH as shown in the truth table.

WRITE TRUTH TABLE(x18)

| к | ĸ | BW ₀ | BW ₁ | OPERATION |
|------------|------------|-----------------|-----------------|---|
| \uparrow | | L | L | WRITE ALL BYTEs (K^{\uparrow}) |
| | \uparrow | L | L | WRITE ALL BYTES ($\overline{\mathbf{K}}\uparrow$) |
| \uparrow | | L | Н | WRITE BYTE 0 (K↑) |
| | \uparrow | L | Н | WRITE BYTE 0 (K̄↑) |
| \uparrow | | Н | L | WRITE BYTE 1 (K↑) |
| | \uparrow | Н | L | WRITE BYTE 1 ($\overline{\mathbf{K}}$) |
| \uparrow | | Н | Н | WRITE NOTHING (K↑) |
| | \uparrow | Н | Н | WRITE NOTHING ($\overline{\mathbf{K}}\uparrow$) |

Notes: 1. X means "Don't Care".

2. All inputs in this table must meet setup and hold time around the rising edge of input clock K or $\overline{\mathsf{K}}$ (\uparrow).

3. Assumes a WRITE cycle was initiated.

WRITE TRUTH TABLE(x36)

| К | ĸ | BW ₀ | BW1 | BW2 | BW3 | OPERATION |
|------------|------------|-----------------|-----|-----|-----|---|
| \uparrow | | L | L | L | L | WRITE ALL BYTEs (K [↑]) |
| | 1 | L | L | L | L | WRITE ALL BYTES ($\overline{\mathbf{K}}$) |
| \uparrow | | L | Н | Н | Н | WRITE BYTE 0 (K↑) |
| | 1 | L | Н | Н | Н | WRITE BYTE 0 ($\overline{\mathbf{K}}^{\uparrow}$) |
| \uparrow | | н | L | Н | Н | WRITE BYTE 1 (K↑) |
| | 1 | Н | L | Н | Н | WRITE BYTE 1 ($\overline{\mathbf{K}}$) |
| \uparrow | | Н | Н | L | L | WRITE BYTE 2 and BYTE 3 (K \uparrow) |
| | \uparrow | н | Н | L | L | WRITE BYTE 2 and BYTE 3 ($\overline{K}\uparrow$) |
| \uparrow | | Н | Н | Н | Н | WRITE NOTHING (K [↑]) |
| | \uparrow | н | Н | Н | Н | WRITE NOTHING (\overline{K}^{\uparrow}) |

Notes: 1. X means "Don't Care".

2. All inputs in this table must meet setup and hold time around the rising edge of input clock K or \overline{K} (\uparrow).

3. Assumes a WRITE cycle was initiated.



1Mx36 & 2Mx18 QDR[™] II+ b4 SRAM

ABSOLUTE MAXIMUM RATINGS

| PARAMETE | ER | SYMBOL | RATING | UNIT |
|--|-------------------------|--------|---------------------|------|
| Voltage on VDD Supply Relative to Vss | | Vdd | -0.5 to 2.9 | V |
| Voltage on VDDQ Supply Relative to Vss | | Vddq | -0.5 to VDD | V |
| Voltage on Input Pin Relative to Vss | | Vin | -0.5 to VDD+0.3 | V |
| Storage Temperature | | Тѕтс | -65 to 150 | °C |
| Operating Temperature | Commercial / Industrial | TOPR | 0 to 70 / -40 to 85 | °C |
| Storage Temperature Range Under Bias | • | TBIAS | -10 to 85 | °C |

Note: 1. Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operating sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

OPERATING CONDITIONS ($0^{\circ}C \le TA \le 70^{\circ}C$)

| PARAMETER | SYMBOL | MIN | ТҮР | MAX | UNIT |
|---------------------------------------|---------|------------|------|------------|------|
| Supply Voltage | Vdd | 1.7 | 1.8 | 1.9 | V |
| Supply Voltage | Vddq | 1.4 | 1.5 | 1.6 | V |
| Reference Voltage | Vref | 0.7 | 0.75 | 0.8 | V |
| Input Low Voltage(DC) ^{2,3)} | VIL(DC) | -0.3 | - | VREF - 0.1 | V |
| Input High Voltage(DC) 2,4) | VIH(DC) | VREF + 0.1 | - | VDDQ + 0.3 | V |
| Input Low Voltage(AC) 6,7) | VIL(AC) | - | - | VREF - 0.2 | V |
| Input Highj Voltage(AC) 6,7) | VIH(AC) | VREF + 0.2 | - | - | V |

Note: 1. VDDQ must not exceed VDD during normal operation.

2. These are DC test criteria. DC design criteria is VREF±50mV. The AC VIH/VIL levels are defined separately for measuring timing parameters.

3. VIL (Min)DC=-0.3V, VIL (Min)AC=-1.5V(pulse width \leq 3ns).

4. VIH (Max)DC=VDDQ+0.3V, VIH (Max)AC=VDDQ+0.85V(pulse width \leq 3ns).

5. Overshoot : VIH (AC) $\leq V\text{DDQ+0.5V}$ for $t \leq$ 50% tKHKH(MIN).

Undershoot: VIL (AC) \leq VSS-0.5V for t \leq 50% tKHKH(MIN).

6. This condition is for AC function test only, not for AC parameter test.

- To maintain a valid level, the transiting edge of the input must:

 a) Sustain a constant slew rate from the current AC level through the target AC level, VIL(AC) or VIH(AC)
 - b) Reach at least the target AC level
 - c) After the AC target level is reached, continue to maintain at least the target DC level, VIL(DC) or VIH(DC)



1Mx36 & 2Mx18 QDR[™] II+ b4 SRAM

DC ELECTRICAL CHARACTERISTICS (VDD=1.8V ±0.1V, TA=0°C to +70°C)

| PARAMETER | SYMBOL | TEST CONDITIONS | | MIN | MAX | UNIT | NOTES |
|------------------------------|--------|--|-----|-------------|-------------|------|-------|
| Input Leakage Current | IIL | VDD=Max ; VIN=Vss to VDDQ | | -2 | +2 | μA | |
| Output Leakage Current | IOL | Output Disabled, | | -2 | +2 | μA | |
| Operating Current (x36): QDR | lcc | VDD=Max , IOUT=0mA | -40 | - | 950 | mA | 1,4 |
| | ICC | Cycle Time ≥ tкнкн Min | -33 | - | 850 | ШA | 1,4 |
| Operating Current (x18): QDR | lcc | VDD=Max , IOUT=0mA -40 | | - | 850 | mA | 1,4 |
| Operating Current (XTO). QDK | ICC | Cycle Time ≥ tкнкн Min | -33 | - | 750 | ШA | 1,4 |
| Standby Current(NOP): QDR | lon (| Device deselected, IOUT=0mA, f=Max, | -40 | - | 350 | mA | 1,5 |
| | ISB1 | All Inputs $\leq 0.2V$ or $\geq V DD - 0.2V$ | -33 | - | 300 | ША | 1,5 |
| Output High Voltage | VOH1 | | | VDDQ/2-0.12 | VDDQ/2+0.12 | V | 2,6 |
| Output Low Voltage | VOL1 | | | VDDQ/2-0.12 | VDDQ/2+0.12 | V | 2,6 |
| Output High Voltage | Voh2 | Іон=-1.0mA | | VDDQ-0.2 | Vddq | V | 3 |
| Output Low Voltage | Vol2 | IoL=1.0mA | | Vss | 0.2 | V | 3 |

Notes: 1. Minimum cycle. IOUT=0mA.

2. $|I_{OH}| = (V_{DDQ}/2)/(RQ/5) \pm 15\%$ for $175\Omega \le RQ \le 350\Omega$. $|I_{OL}| = (V_{DDQ}/2)/(RQ/5) \pm 15\%$ for $175\Omega \le RQ \le 350\Omega$.

3. Minimum Impedance Mode when ZQ pin is connected to VDD.

4. Operating current is calculated with 50% read cycles and 50% write cycles.

5. Standby Current is only after all pending read and write burst operations are completed.

6. Programmable Impedance Mode.



1Mx36 & 2Mx18 QDR[™] II+ b4 SRAM

AC TIMING CHARACTERISTICS (VDD=1.8V±0.1V, TA=0°C to +70°C)

| | | -4 | 40 | | 33 | | |
|--|------------------|-------|------|-------|------|-------|------|
| PARAMETER | SYMBOL - | MIN | MAX | MIN | MAX | UNIT | NOTE |
| Clock | II | | | | | | |
| Clock Cycle Time (K, K) | tкнкн | 2.5 | 8.4 | 3.0 | 8.4 | ns | |
| Clock Phase Jitter (K, \overline{K}) | tK var | | 0.20 | | 0.20 | ns | 4 |
| Clock High Time (K, \overline{K}) | t KHKL | 0.4 | | 0.4 | | ns | |
| Clock Low Time (K, \overline{K}) | t KLKH | 0.4 | | 0.4 | | ns | - |
| Clock to $\overline{\text{Clock}}$ (K $\uparrow \rightarrow \overline{\text{K}}\uparrow$) | tкнкн | 1.06 | | 1.3 | | ns | |
| DLL Lock Time (K) | tK lock | 2048 | | 2048 | | cycle | 5 |
| K Static to DLL reset | t K reset | 30 | | 30 | | ns | |
| Output Times | 1 1 | | 1 | L | | 1 | |
| K, K High to Output Valid | t KHQV | | 0.45 | | 0.45 | ns | |
| K, K High to Output Hold | tкнqх | -0.45 | | -0.45 | | ns | |
| K, K High to Echo Clock Valid | tкнсqv | | 0.45 | | 0.45 | ns | |
| K, \overline{K} High to Echo Clock Hold | tкнсqх | -0.45 | | -0.45 | | ns | |
| CQ, CQ High to Output Valid | t CQHQV | | 0.2 | | 0.2 | ns | - |
| CQ, CQ High to Output Hold | tсанах | -0.2 | | -0.2 | | ns | |
| CQ High to CQ High | tcqHcqH | 0.86 | | 1.1 | | ns | 6 |
| K, K High to Output High-Z | tкнz | | 0.45 | | 0.45 | ns | |
| K, K High to Output Low-Z | tĸlz | -0.45 | | -0.45 | | ns | |
| CQ, CQ High to QVLD Valid | t QVLD | -0.2 | 0.2 | -0.2 | 0.2 | ns | |
| Setup Times | 1 1 | | 1 | L | 1 | 1 | |
| Address valid to K rising edge | tavкн | 0.40 | | 0.40 | | ns | |
| Control inputs valid to K rising edge | tıvкн | 0.40 | | 0.40 | | ns | 2 |
| Data-in valid to K, \overline{K} rising edge | tdvкн | 0.28 | | 0.28 | | ns | |
| Hold Times | | | | | | • | |
| K rising edge to address hold | t KHAX | 0.40 | | 0.40 | | ns | |
| K rising edge to control inputs hold | tкніх | 0.40 | | 0.40 | | ns | |
| K, \overline{K} rising edge to data-in hold | t KHDX | 0.28 | | 0.28 | | ns | |

Notes: 1. All address inputs <u>must meet the specified setup</u> and hold times for all latching clock edges. 2. Control singles are R, W.

However BWx does not apply to this parameters. BWx signals obey the data setup and hold times.

3. To avoid bus contention, at a given voltage and temperature tKLZ is bigger than tKHZ. The specs as shown do not imply bus contention because tKLZ is a MIN parameter that is worst case at totally different test conditions (0°C, 1.9V) than tKHZ, which is a MAX parameter(worst case at 70°C, 1.7V)

It is not possible for two SRAMs on the same board to be at such different voltage and temperature.

Clock phase jitter is the variance from clock rising edge to the next expected clock rising edge.
 Vdd slew rate must be less than 0.1V DC per 50 ns for DLL lock retention. DLL lock time begins once Vdd and input clock are stable.

6. This parameter is extrapolated from the input timing parameters (tKHKH - 200ps where 200ps is the internal jitter.) This parameter is only guaranteed by design and not tested in production.



1Mx36 & 2Mx18 QDR[™] II+ b4 SRAM

THERMAL RESISTANCE

| PRMETER | SYMBOL | ТҮР | Unit | NOTES |
|---------------------|--------|------|------|-------|
| Junction to Ambient | θJA | 20.8 | °C/W | |
| Junction to Case | θJC | 2.3 | °C/W | |
| Junction to Pins | θјв | 4.3 | °C/W | |

Note: Junction temperature is a function of on-chip power dissipation, package thermal impedance, mounting site temperature and mounting site thermal impedance. TJ=TA + PD x 0JA

PIN CAPACITANCE

| PRMETER | SYMBOL | TESTCONDITION | ТҮР | MAX | Unit | NOTES |
|-----------------------------------|--------|---------------|-----|-----|------|-------|
| Address Control Input Capacitance | CIN | VIN=0V | 3.5 | 4 | pF | |
| Input and Output Capacitance | Соит | Vout=0V | 4 | 5 | pF | |
| Clock Capacitance | CCLK | - | 3 | 4 | pF | |

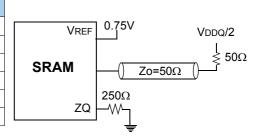
Note: 1. Parameters are tested with RQ=250 Ω and VDDQ=1.5V.

2. Periodically sampled and not 100% tested.

AC TEST CONDITIONS

| Parameter | Symbol | Value | Unit |
|-------------------------------|---------|-----------|------|
| Core Power Supply Voltage | Vdd | 1.7~1.9 | V |
| Output Power Supply Voltage | Vddq | 1.4~1.6 | V |
| Input High/Low Level | VIH/VIL | 1.25/0.25 | V |
| Input Reference Level | VREF | 0.75 | V |
| Input Rise/Fall Time | Tr/Tf | 0.3/0.3 | ns |
| Output Timing Reference Level | | VDDQ/2 | V |

AC TEST OUTPUT LOAD

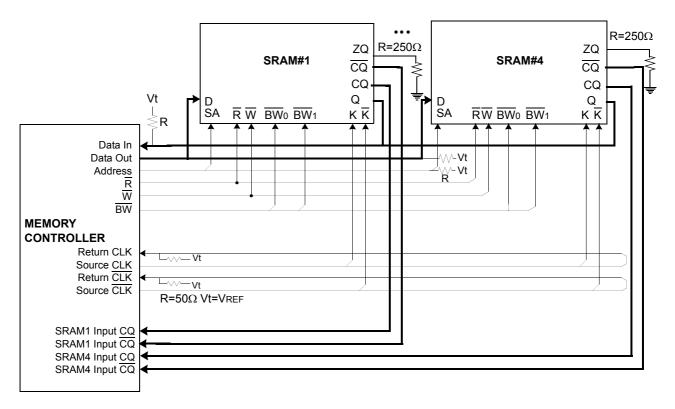


Note: Parameters are tested with RQ=250 Ω



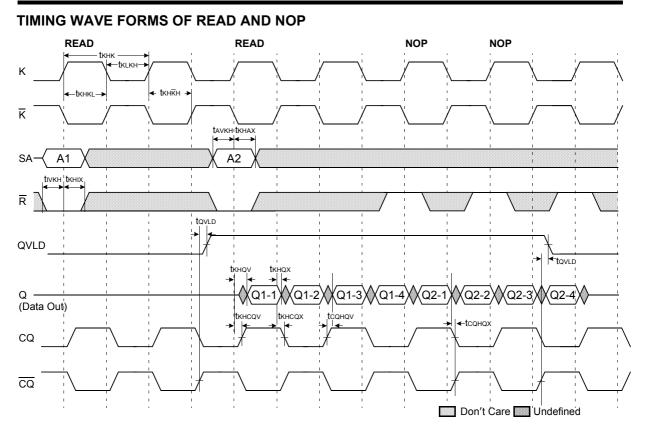
1Mx36 & 2Mx18 QDR[™] II+ b4 SRAM

APPLICATION INRORMATION

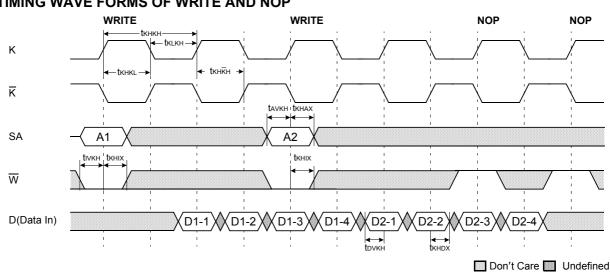




1Mx36 & 2Mx18 QDR[™] II+ b4 SRAM



Note: 1. Q1-1 refers to output from address A1+0, Q1-2 refers to output from address A1+1 i.e. the next internal burst address following A1+0. 2. Outputs are disabled one cycle after a NOP.



TIMING WAVE FORMS OF WRITE AND NOP

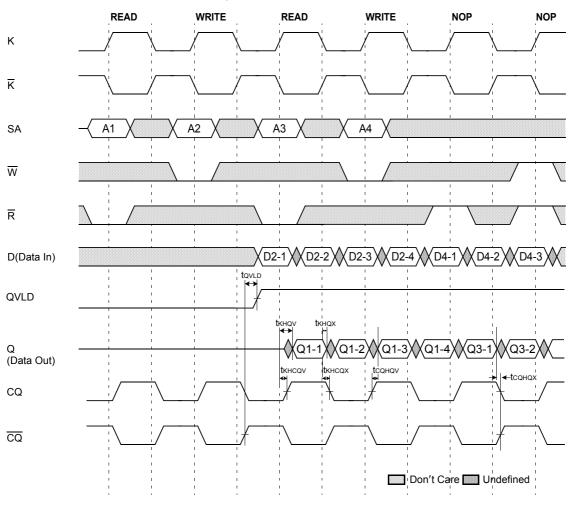
Note: 1. D1-1 refers to input to address A1+0, D1-2 refers to input to address A1+1, i.e the next internal burst address following A1+0. 2. BWx assumed active.



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K7S3236T4C K7S3218T4C

1Mx36 & 2Mx18 QDR[™] II+ b4 SRAM



TIMING WAVE FORMS OF READ, WRITE AND NOP

Note: 1. If address A3=A2, data Q3-1=D2-1, data Q3-2=D2-2, data Q3-3=D2-3, data Q3-4=D2-4 Write data is forwarded immediately as read results. 2.BWx assumed active.

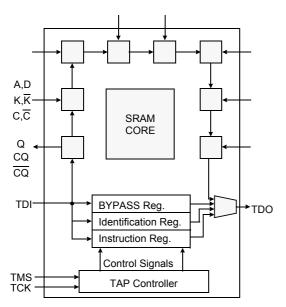


1Mx36 & 2Mx18 QDR[™] II+ b4 SRAM

IEEE 1149.1 TEST ACCESS PORT AND BOUNDARY SCAN-JTAG

This part contains an IEEE standard 1149.1 Compatible Test Access Port(TAP). The package pads are monitored by the Serial Scan circuitry when in test mode. This is to support connectivity testing during manufacturing and system diagnostics. Internal data is not driven out of the SRAM under JTAG control. In conformance with IEEE 1149.1, the SRAM contains a TAP controller, Instruction Register, Bypass Register and ID register. The TAP controller has a standard 16-state machine that resets internally upon power-up, therefore, TRST signal is not required. It is possible to use this device without utilizing the TAP. To disable the TAP controller without interfacing with normal operation of the SRAM, TCK must be tied to Vss to preclude mid level input. TMS and TDI are designed so an undriven input will produce a response identical to the application of a logic 1, and may be left unconnected. But they may also be tied to Vbp through a resistor. TDO should be left unconnected.

JTAG Block Diagram



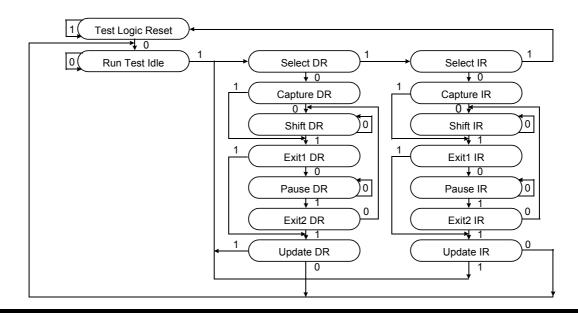
JTAG Instruction Coding

| IR2 | IR1 | IR0 | IR0 Instruction TDO Output | | Notes |
|-----|-----|-----|----------------------------|-------------------------|-------|
| 0 | 0 | 0 | EXTEST | Boundary Scan Register | 1 |
| 0 | 0 | 1 | IDCODE | Identification Register | 3 |
| 0 | 1 | 0 | SAMPLE-Z | Boundary Scan Register | 2 |
| 0 | 1 | 1 | RESERVED | Do Not Use | 6 |
| 1 | 0 | 0 | SAMPLE | Boundary Scan Register | 5 |
| 1 | 0 | 1 | RESERVED | Do Not Use | 6 |
| 1 | 1 | 0 | RESERVED | Do Not Use | 6 |
| 1 | 1 | 1 | BYPASS | Bypass Register | 4 |

NOTE:

- 1. Places DQs in Hi-Z in order to sample all input data regardless of other SRAM inputs. This instruction is not IEEE 1149.1 compliant.
- 2. Places DQs in Hi-Z in order to sample all input data regardless of other SRAM inputs.
- 3. TDI is sampled as an input to the first ID register to allow for the serial shift of the external TDI data.
- Bypass register is initiated to Vss when BYPASS instruction is invoked. The Bypass Register also holds serially loaded TDI when exiting the Shift DR states.
- 5. SAMPLE instruction dose not places DQs in Hi-Z.
- 6. This instruction is reserved for future use.

TAP Controller State Diagram





Rev. 1.3 August 2008

1Mx36 & 2Mx18 QDR[™] II+ b4 SRAM

SCAN REGISTER DEFINITION

| Part | Instruction Register Bypass Register ID Register | | Boundary Scan | |
|-------|--|-------|---------------|----------|
| 1Mx36 | 3 bits | 1 bit | 32 bits | 109 bits |
| 2Mx18 | 3 bits | 1 bit | 32 bits | 109 bits |

ID REGISTER DEFINITION

| Part | Revision Number (31:29) | Part Configuration (28:12) | Samsung JEDEC Code (11: 1) | Start Bit(0) |
|-------|----------------------------|-------------------------------|-------------------------------|--------------|
| 1Mx36 | 000 | 00def0wx0t0q0b0s0 | 00011001110 | 1 |
| 2Mx18 | 000 | 00def0wx0t0q0b0s0 | 00011001110 | 1 |

Note : Part Configuration

/def=010 for 36Mb, /wx=11 for x36, 10 for x18

/t=1 for DLL Ver., 0 for non-DLL Ver. /q=1 for QDR, 0 for DDR /b=1 for 4Bit Burst, 0 for 2Bit Burst /s=1 for Separate I/O, 0 for Common I/O

BOUNDARY SCAN EXIT ORDER

| 1 $6R$ 37 $10D$ 2 $6P$ 38 $9E$ 3 $6N$ 39 $10C$ 4 $7P$ 40 $11D$ 5 $7N$ 41 $9C$ 6 $7R$ 42 $9D$ 7 $8R$ 43 $11B$ 8 $8P$ 44 $11C$ 9 $9R$ 44 $11C$ 9 $9R$ 44 $11C$ 11 $10P$ 47 $11A$ 12 $10N$ 48 $10A$ 13 $9P$ 49 $9A$ 14 $10M$ 50 $8B$ 15 $11N$ 51 $7C$ 16 $9M$ 52 $6C$ 88 $3J$ 16 $9M$ 52 $6C$ 88 $3J$ 20 $9L$ 56 21 $10L$ 22 $11K$ 22 $11K$ 24 $9J$ 24 $9J$ 26 $10J$ 26 $10J$ 26 $10J$ 27 $11J$ 62 48 99 $3P$ 28 $11H$ 62 48 99 $3P$ 28 $11H$ 61 $5C$ 66 $1A$ $910G$ 66 28 1102 $1P$ 31 $11F$ 67 38 32 $11G$ 34 $10F$ 35 $11E$ 71 $3C$ <th>ORDER</th> <th>PIN ID</th> <th>ORDER</th> <th>PIN ID</th> <th>ORDER</th> <th>PIN ID</th> | ORDER | PIN ID | ORDER | PIN ID | ORDER | PIN ID |
|--|-------|--------|-------|--------|-------|--------|
| 2 $6P$ 38 $9E$ 74 $3E$ 3 $6N$ 39 $10C$ 75 $2D$ 4 $7P$ 40 $11D$ 76 $2E$ 5 $7N$ 41 $9C$ 77 $1E$ 6 $7R$ 42 $9D$ 78 $2F$ 7 $8R$ 42 $9D$ 78 $2F$ 9 $9R$ 44 $11C$ 80 16 9 $9R$ 44 $11C$ 80 16 9 $9R$ 44 $11C$ 80 16 11 $10P$ 47 $11A$ 86 $2G$ 12 $10N$ 48 $10A$ 84 $1H$ 13 $9P$ 49 $9A$ 86 $2J$ 16 $9M$ 51 $7C$ $8R$ 86 $2J$ 16 $9M$ 51 $7C$ $8R$ 86 $2J$ 16 $9M$ 51 $7C$ $8R$ 89 $2K$ 18 $11L$ 54 $7A$ 90 $1K$ 20 $9L$ 56 $6B$ 92 $3L$ 21 $10L$ 57 $6A$ 93 $1M$ 22 $11K$ 58 $5B$ 94 $1L$ 23 $10K$ 66 $2B$ 94 $1L$ 26 $0J$ 66 $2R$ 99 $3R$ 27 $11J$ 66 $2R$ 99 $3P$ 28 $11H$ 66 $2R$ 99 $3R$ 29 $10G$ | 1 | 6R | 37 | 10D | 73 | 2C |
| 3 $6N$ 39 $10C$ 75 $2D$ 4 $7P$ 40 $11D$ 76 $2E$ 5 $7N$ 41 $9C$ 77 $1E$ 6 $7R$ 42 $9D$ 78 $2f$ 7 $8R$ 43 $11B$ 80 $1G$ 8 $8P$ 44 $11C$ 80 $1G$ 9 $9R$ 45 $9B$ 81 $1F$ 10 $11P$ 46 $10B$ 82 $3G$ 11 $10P$ 47 $11A$ 83 $2G$ 12 $10N$ 48 $10A$ 84 $1H$ 13 $9P$ 49 $9A$ 86 $2J$ 14 $10M$ 50 $8B$ 86 $2J$ 15 $11N$ 51 $7C$ 87 $8K$ 16 $9M$ 52 66 86 $3J$ 17 $9N$ 53 $8A$ 86 $2J$ 18 $11L$ 55 $7B$ 91 $2L$ 20 $9L$ 56 66 92 $3L$ 21 $10L$ 57 $6A$ 93 $1M$ 22 $11K$ 58 58 94 $1L$ 23 $10K$ 62 48 94 $1L$ 24 $9J$ 61 $5C$ 97 $1N$ 25 $9K$ 61 $5C$ 98 $2M$ 26 $10J$ 65 $1A$ 100 $2N$ 29 $10G$ 66 $2B$ 102 | | | | | 74 | 3E |
| 4 $7P$ 40 $11D$ 76 $2E$ 5 $7N$ 41 $9C$ 77 $1E$ 6 $7R$ 42 $9D$ 78 $2F$ 7 $8R$ 43 $11B$ 79 $3F$ 8 $8P$ 44 $11C$ 80 $1G$ 9 $9R$ 45 $9B$ 81 $1F$ 10 $11P$ 46 $10B$ 82 $3G$ 11 $10P$ 47 $11A$ 84 $1H$ 13 $9P$ 49 $9A$ 85 $1J$ 14 $10M$ 50 $8B$ 86 $2J$ 15 $11N$ 51 $7C$ 87 $3K$ 16 $9M$ 52 $6C$ 88 $3J$ 17 $9N$ 53 $8A$ 89 $2K$ 18 $11L$ 54 $7A$ 90 $1K$ 19 $11M$ 55 $7B$ 91 $2L$ 20 $9L$ 56 $6B$ 92 $3L$ 21 $10L$ 57 $6A$ 93 $1M$ 24 $9J$ 60 $4A$ 96 $3M$ 25 $9K$ 61 $5C$ 97 $1N$ 26 $10J$ 62 $4B$ 99 $3P$ 28 $11H$ 64 $2A$ 100 $2N$ 31 $11F$ 67 $3B$ 103 $3R$ 32 $11G$ 66 12 101 $2P$ 33 $9F$ 60 18 <td></td> <td>6N</td> <td></td> <td></td> <td>75</td> <td>2D</td> | | 6N | | | 75 | 2D |
| 5 $7N$ 41 $9C$ 77 $1E$ 6 $7R$ 42 $9D$ 78 $2F$ 7 $8R$ 43 $11B$ 79 $3F$ 8 $8P$ 44 $11C$ 80 $1G$ 9 $9R$ 45 $9B$ 81 $1F$ 10 $11P$ 46 $10B$ 82 $3G$ 11 $10P$ 47 $11A$ 84 $1H$ 13 $9P$ 49 $9A$ 85 $1J$ 14 $10M$ 50 $8B$ 86 $2J$ 15 $11N$ 51 $7C$ 87 $3K$ 16 $9M$ 52 $6C$ 88 $3J$ 17 $9N$ 53 $8A$ 89 $2K$ 18 $11L$ 54 $7A$ 90 $1K$ 20 $9L$ 56 $6B$ 92 $3L$ 21 $10L$ 57 $6A$ 93 $1M$ 22 $11K$ 58 $5B$ 94 $1L$ 23 $10K$ 66 $4A$ 96 $3M$ 24 $9J$ 60 $4A$ 96 $3M$ 25 $9K$ 61 $5C$ 98 $2M$ 26 $10J$ 65 $1A$ 100 $2N$ 28 $11H$ 64 $2A$ 100 $2N$ 32 $11G$ 66 $2B$ 102 $1P$ 33 $9F$ 66 $2B$ 103 $3R$ 32 | | 7P | 40 | 11D | 76 | 2E |
| 6 $7R$ 42 $9D$ 78 $2F$ 7 $8R$ 43 $11B$ 79 $3F$ 8 $8P$ 44 $11C$ 80 $1G$ 9 $9R$ 445 $9B$ 81 $1F$ 10 $11P$ 46 $10B$ 82 $3G$ 11 $10P$ 47 $11A$ 833 $2G$ 11 $10P$ 47 $11A$ 84 $1H$ 13 $9P$ 49 $9A$ 86 $2J$ 14 $10M$ 50 $8B$ 86 $2J$ 15 $11N$ 51 $7C$ 87 $3K$ 16 $9M$ 52 $6C$ 88 $3J$ 17 $9N$ 53 $8A$ 89 $2K$ 18 $11L$ 55 $7B$ 91 $2L$ 20 $9L$ 57 $6A$ 92 $3L$ 21 $10L$ 57 $6A$ 92 $3L$ 22 $11K$ 59 $5A$ 94 $1L$ 23 $10K$ 59 $5A$ 95 $3N$ 24 $9J$ 66 $2B$ 99 $3P$ 27 $11J$ 63 $3A$ 99 $3P$ 28 $11H$ 64 $2A$ 100 $2N$ 31 $11F$ 67 $3B$ 103 $3R$ 32 $11G$ 66 $1B$ 103 $3R$ 33 $9F$ 70 $3D$ 106 $5P$ 34 <td></td> <td></td> <td></td> <td></td> <td>77</td> <td>1E</td> | | | | | 77 | 1E |
| 78R4311B88P4411C99R459B1011P4610B1110P4711A1210N4810A139P499A1410M508B51517C557B87169M526C1811L547A1911M557B209L566B2110L576A2211K595A2310K595A2610J624B2711J633A2811H642A309G662B3111F673B3211G681C339F691B3511E713C | | | | | 78 | 2F |
| 88P4411C801G99R459B 81 1F1011P4610B 82 3G1110P4711A 83 2G1210N4810A 84 1H139P499A 86 2J1410M508B 86 2J1511N517C 87 $3K$ 169M526C 88 $3J$ 179N53 $8A$ 89 $2K$ 1811L547A 90 1K1911M557B 91 $2L$ 209L56 $6B$ 92 $3L$ 2110L57 $6A$ 93 $1M$ 2211K 58 $5B$ 95 $3N$ 249J 60 $4A$ 95 $3N$ 259K 61 $5C$ 97 $1N$ 2610J 62 $4B$ 98 $2M$ 2711J 63 $3A$ 99 $3P$ 2811H 64 $2A$ 98 $2M$ 31 11F 67 $3B$ 103 $3R$ 32 11G 68 $1C$ 104 $4R$ 33 $9F$ 69 $1B$ 105 $4P$ 34 $10F$ 71 $3C$ 107 $5N$ | | | | | 79 | 3F |
| 99R 45 9B 81 $1F$ 10 $11P$ 46 $10B$ 82 $3G$ 11 $10P$ 47 $11A$ 83 $2G$ 12 $10N$ 48 $10A$ 84 $11H$ 13 $9P$ $9A$ 86 $2J$ 14 $10M$ 50 $8B$ 86 $2J$ 15 $11N$ 51 $7C$ 87 $3K$ 16 $9M$ 52 $6C$ 88 $3J$ 17 $9N$ 53 $8A$ 90 $1K$ 18 $11L$ 55 $7B$ 91 $2L$ 20 $9L$ 56 $6B$ 92 $3L$ 21 $10L$ 57 $6A$ 99 $3N$ 22 $11K$ 58 $5B$ 94 $1L$ 23 $10K$ 60 $4A$ 96 $3M$ 24 $9J$ 66 $4B$ 99 $3P$ 25 $9K$ 61 $5C$ 97 $1N$ 26 $10J$ 63 $3A$ 99 $3P$ 28 $11H$ 64 $2A$ 99 $3P$ 30 $9G$ 66 $2B$ 102 $1P$ 31 $11F$ 67 $3B$ 103 $3R$ 32 $11G$ 69 $1B$ 105 $4P$ 33 $9F$ 69 $1B$ 105 $4P$ 34 $10F$ 71 $3C$ 107 $5N$ | | | | | 80 | 1G |
| 10 $11P$ 46 $10B$ 82 $3G$ 11 $10P$ 47 $11A$ 83 $2G$ 12 $10N$ 48 $10A$ 84 $1H$ 13 $9P$ 49 $9A$ 85 $1J$ 14 $10M$ 50 $8B$ 86 $2J$ 15 $11N$ 51 $7C$ 87 $3K$ 16 $9M$ 52 $6C$ 88 $3J$ 17 $9N$ 53 $8A$ 89 $2K$ 18 $11L$ 54 $7A$ 900 $1K$ 19 $11M$ 55 $7B$ 900 $1K$ 20 $9L$ 56 $6B$ 92 $3L$ 21 $10L$ 57 $6A$ 93 $1M$ 22 $11K$ 58 $5B$ 94 $1L$ 23 $10K$ 59 $5A$ 94 $1L$ 26 $10J$ 66 $2B$ 95 $3M$ 27 $11J$ 64 $2A$ 99 $9P$ 31 $11F$ 66 $2B$ 100 $2N$ 33 $9F$ 66 $2B$ 102 $1P$ 31 $11F$ 67 $3B$ 104 $4R$ 33 $9F$ 69 $1B$ 105 $4P$ 34 $10F$ 71 $3C$ 107 $5N$ | | | | | 81 | 1F |
| 1110P4711A 83 2G1210N4810A 84 1H139P499A 86 $2J$ 1410M508B 86 $2J$ 1511N517C 87 $3K$ 169M 52 $6C$ 88 $3J$ 179N53 $8A$ 89 $2K$ 1811L 54 $7A$ 90 $1K$ 1911M 55 $7B$ 91 $2L$ 209L 56 $6B$ 92 $3L$ 2110L 57 $6A$ 93 $1M$ 2211K 58 $5B$ 94 $1L$ 2310K 59 $5A$ 95 $3N$ 249J 60 $4A$ 96 $3M$ 25 $9K$ 61 $5C$ 97 $1N$ 26 $10J$ 62 $4B$ 98 $2M$ 27 $11J$ 64 $2A$ 99 $3P$ 30 $9G$ 66 $2B$ 100 $2N$ 31 $11F$ 67 $3B$ 103 $3R$ 32 116 68 $1C$ 104 $4R$ 33 $9F$ 36 $1B$ 104 $4R$ 35 $11E$ 71 $3C$ 107 $5N$ | | | 46 | 10B | 82 | 3G |
| 12 $10N$ 48 $10A$ 84 $1H$ 13 $9P$ 49 $9A$ 85 $1J$ 14 $10M$ 50 $8B$ 86 $2J$ 15 $11N$ 51 $7C$ 87 $3K$ 16 $9M$ 52 $6C$ 88 $3J$ 17 $9N$ 53 $8A$ 89 $2K$ 18 $11L$ 55 $7B$ 90 $1K$ 19 $11M$ 55 $7B$ 91 $2L$ 20 $9L$ 56 $6B$ 92 $3L$ 21 $10L$ 57 $6A$ 93 $1M$ 22 $11K$ 58 $5B$ 94 $1L$ 23 $10K$ 59 $5A$ 94 $1L$ 24 $9J$ 60 $4A$ 96 $3M$ 24 $9J$ 62 $4B$ 99 $3P$ 28 $11H$ 64 $2A$ 99 $3P$ 28 $11H$ 64 $2A$ 100 $2N$ 29 $10G$ 66 $2B$ 102 $1P$ 31 $11F$ 67 $3B$ 103 $3R$ 32 $11G$ 68 $1C$ 104 $4R$ 33 $9F$ 69 $1B$ 105 $4P$ 34 $10F$ 71 $3C$ 107 $5N$ | | 10P | | | 83 | 2G |
| 139P499A1410M1511N1511N169M526C883J179N538A1811L547A901K209L209L209L566B2211K2310K249J615C2610J2610J2711J633A993P2811H642A1066629106651A309F3410F3511E713C | | | | | 84 | 1H |
| 14 $10M$ 50 $8B$ 86 $2J$ 15 $11N$ 51 $7C$ 87 $3K$ 16 $9M$ 52 $6C$ 88 $3J$ 17 $9N$ 53 $8A$ 89 $2K$ 18 $11L$ 54 $7A$ 90 $1K$ 19 $11M$ 55 $7B$ 91 $2L$ 20 $9L$ 56 $6B$ 92 $3L$ 21 $10L$ 57 $6A$ 93 $1M$ 22 $11K$ 58 $5B$ 94 $1L$ 23 $10K$ 59 $5A$ 94 $1L$ 23 $10K$ 59 $5A$ 96 $3M$ 24 $9J$ 60 $4A$ 96 $3M$ 25 $9K$ 61 $5C$ 97 $1N$ 26 $10J$ 62 $4B$ 99 $3P$ 28 $11H$ 64 $2A$ 99 $3P$ 30 $9G$ 66 $2B$ 100 $2N$ 31 $11F$ 66 $1C$ 101 $2P$ 33 $9F$ 69 $1B$ 103 $3R$ 34 $10F$ 70 $3D$ 106 $5P$ 35 $11E$ 71 $3C$ 107 $5N$ | | | | | 85 | 1J |
| 15 $11N$ 51 $7C$ 87 $3K$ 16 $9M$ 52 $6C$ 88 $3J$ 17 $9N$ 53 $8A$ 89 $2K$ 18 $11L$ 54 $7A$ 90 $1K$ 19 $11M$ 55 $7B$ 91 $2L$ 20 $9L$ 56 $6B$ 92 $3L$ 21 $10L$ 57 $6A$ 93 $1M$ 22 $11K$ 58 $5B$ 94 $1L$ 23 $10K$ 59 $5A$ 94 $1L$ 24 $9J$ 60 $4A$ 96 $3M$ 25 $9K$ 61 $5C$ 97 $1N$ 26 $10J$ 62 $4B$ 98 $2M$ 27 $11J$ 63 $3A$ 99 $3P$ 28 $11H$ 64 $2A$ 100 $2N$ 29 $10G$ 66 $2B$ 103 $3R$ 31 $11F$ 67 $3B$ 103 $3R$ 32 $11G$ 68 $1C$ 104 $4R$ 33 $9F$ 69 $1B$ 105 $4P$ 34 $10F$ 71 $3C$ 107 $5N$ | | | | | 86 | 2J |
| 16 $9M$ 52 $6C$ 88 $3J$ 17 $9N$ 53 $8A$ 89 $2K$ 18 $11L$ 54 $7A$ 90 $1K$ 19 $11M$ 55 $7B$ 91 $2L$ 20 $9L$ 56 $6B$ 92 $3L$ 21 $10L$ 57 $6A$ 93 $1M$ 22 $11K$ 58 $5B$ 94 $1L$ 23 $10K$ 59 $5A$ 94 $1L$ 23 $10K$ 59 $5A$ 95 $3N$ 24 $9J$ 60 $4A$ 96 $3M$ 25 $9K$ 61 $5C$ 97 $1N$ 26 $10J$ 62 $4B$ 99 $3P$ 28 $11H$ 64 $2A$ 99 $3P$ 30 $9G$ 66 $2B$ 100 $2N$ 31 $11F$ 67 $3B$ 103 $3R$ 32 $11G$ 68 $1C$ 104 $4R$ 33 $9F$ 69 $1B$ 105 $4P$ 34 $10F$ 71 $3C$ 107 $5N$ | | | | | 87 | ЗK |
| 17 $9N$ 53 $8A$ 89 $2K$ 18 $11L$ 54 $7A$ 90 $1K$ 19 $11M$ 55 $7B$ 91 $2L$ 20 $9L$ 56 $6B$ 92 $3L$ 21 $10L$ 57 $6A$ 93 $1M$ 22 $11K$ 58 $5B$ 94 $1L$ 23 $10K$ 59 $5A$ 94 $1L$ 24 $9J$ 60 $4A$ 96 $3M$ 24 $9J$ 61 $5C$ $9K$ 61 $5C$ 26 $10J$ 62 $4B$ 99 $3P$ 28 $11H$ 64 $2A$ 99 $3P$ 28 $11H$ 64 $2A$ 100 $2N$ 29 $10G$ 65 $1A$ 101 $2P$ 30 $9G$ 66 $2B$ 102 $1P$ 31 $11F$ 67 $3B$ 103 $3R$ 32 $11G$ 68 $1C$ 104 $4R$ 33 $9F$ 69 $1B$ 105 $4P$ 34 $10F$ 71 $3C$ 107 $5N$ | | | | | 88 | 3J |
| 18 $11L$ 54 $7A$ 90 $1K$ 19 $11M$ 55 $7B$ 91 $2L$ 20 $9L$ 56 $6B$ 92 $3L$ 21 $10L$ 57 $6A$ 93 $1M$ 22 $11K$ 58 $5B$ 94 $1L$ 23 $10K$ 59 $5A$ 94 $1L$ 23 $10K$ 59 $5A$ 95 $3N$ 24 $9J$ 60 $4A$ 96 $3M$ 25 $9K$ 61 $5C$ 97 $1N$ 26 $10J$ 62 $4B$ 98 $2M$ 27 $11J$ 63 $3A$ 99 $3P$ 28 $11H$ 64 $2A$ 100 $2N$ 29 $10G$ 66 $2B$ 102 $1P$ 31 $11F$ 67 $3B$ 103 $3R$ 32 $11G$ 68 $1C$ 104 $4R$ 33 $9F$ 69 $1B$ 106 $5P$ 34 $10F$ 71 $3C$ 107 $5N$ | | | | | 89 | 2K |
| 19 $11M$ 55 $7B$ 91 $2L$ 20 $9L$ 56 $6B$ 92 $3L$ 21 $10L$ 57 $6A$ 93 $1M$ 22 $11K$ 58 $5B$ 94 $1L$ 23 $10K$ 59 $5A$ 95 $3N$ 24 $9J$ 60 $4A$ 96 $3M$ 25 $9K$ 61 $5C$ 97 $1N$ 26 $10J$ 62 $4B$ 98 $2M$ 27 $11J$ 63 $3A$ 99 $3P$ 28 $11H$ 64 $2A$ 100 $2N$ 29 $10G$ 65 $1A$ 101 $2P$ 30 $9G$ 66 $2B$ 102 $1P$ 31 $11F$ 67 $3B$ 103 $3R$ 32 $11G$ 68 $1C$ 104 $4R$ 33 $9F$ 69 $1B$ 105 $4P$ 34 $10F$ 70 $3D$ 106 $5P$ 35 $11E$ 71 $3C$ 107 $5N$ | 18 | 11L | | | 90 | 1K |
| $ \begin{array}{c ccccccccccccccccccccccccccccccccccc$ | | | 55 | | 91 | 2L |
| 21 10L 22 11K 23 10K 23 10K 24 9J 25 9K 61 5C 96 3M 27 11J 63 3A 99 3P 28 11H 64 2A 99 3P 30 9G 66 2B 31 11F 67 3B 32 11G 63 1C 64 2A 101 2P 102 1P 103 3R 11F 67 68 1C 103 3R 104 4R 105 4P 106 5P 34 10F 35 11E | | | | | 92 | 3L |
| 22 11K 23 10K 23 10K 24 9J 25 9K 61 5C 62 4B 97 1N 63 3A 99 3P 28 11H 64 2A 99 3P 66 2B 101 2P 30 9G 66 2B 31 11F 67 3B 102 1P 103 3R 32 11G 33 9F 34 10F 71 3C | | | | | 93 | 1M |
| 23 10K 59 5A 95 3N 24 9J 60 4A 96 3M 25 9K 61 5C 97 1N 26 10J 62 4B 98 2M 27 11J 63 3A 99 3P 28 11H 64 2A 100 2N 29 10G 65 1A 101 2P 30 9G 66 2B 102 1P 31 11F 67 3B 103 3R 32 11G 68 1C 104 4R 33 9F 69 1B 105 4P 34 10F 71 3C 107 5N | | | | | 94 | 1L |
| 24 9J 60 4A 96 3M 25 9K 61 5C 97 1N 26 10J 62 4B 98 2M 27 11J 63 3A 99 3P 28 11H 64 2A 100 2N 29 10G 65 1A 101 2P 30 9G 66 2B 102 1P 31 11F 67 3B 103 3R 32 11G 68 1C 104 4R 33 9F 69 1B 105 4P 34 10F 71 3C 107 5N | | | | | 95 | 3N |
| 25 9K 61 5C 97 1N 26 10J 62 4B 98 2M 27 11J 63 3A 99 3P 28 11H 64 2A 100 2N 30 9G 66 2B 101 2P 31 11F 67 3B 102 1P 32 11G 68 1C 104 4R 33 9F 69 1B 105 4P 34 10F 71 3C 107 5N | | | | | 96 | 3M |
| 26 10J 62 4B 98 2M 27 11J 63 3A 99 3P 28 11H 64 2A 100 2N 29 10G 65 1A 101 2P 30 9G 66 2B 102 1P 31 11F 67 3B 103 3R 32 11G 68 1C 104 4R 33 9F 69 1B 105 4P 34 10F 71 3C 107 5N | | | | | 97 | 1N |
| 27 11J 63 3A 28 11H 29 10G 30 9G 31 11F 66 2B 31 11F 67 3B 32 11G 68 1C 33 9F 34 10F 70 3D 106 5P 107 5N | | | | | 98 | 2M |
| 28 11H 64 2A 100 2N 29 10G 65 1A 101 2P 30 9G 66 2B 102 1P 31 11F 67 3B 103 3R 32 11G 68 1C 104 4R 33 9F 69 1B 105 4P 34 10F 70 3D 106 5P 35 11E 71 3C 107 5N | 27 | 11J | | | 99 | 3P |
| 29 10G 65 1A 101 2P 30 9G 66 2B 102 1P 31 11F 67 3B 103 3R 32 11G 68 1C 104 4R 33 9F 69 1B 105 4P 34 10F 70 3D 106 5P 35 11E 71 3C 107 5N | | | | | 100 | 2N |
| 30 9G 66 2B 102 1P 31 11F 67 3B 103 3R 32 11G 68 1C 104 4R 33 9F 69 1B 105 4P 34 10F 70 3D 106 5P 35 11E 71 3C 107 5N | 29 | 10G | | | 101 | 2P |
| 31 11F 67 3B 103 3R 32 11G 68 1C 104 4R 33 9F 69 1B 105 4P 34 10F 70 3D 106 5P 35 11E 71 3C 107 5N | 30 | | 66 | 2B | 102 | 1P |
| 32 11G 68 1C 104 4R 33 9F 69 1B 105 4P 34 10F 70 3D 106 5P 35 11E 71 3C 107 5N | | | | | 103 | 3R |
| 33 9F 69 1B 105 4P 34 10F 70 3D 106 5P 35 11E 71 3C 107 5N | | | | | 104 | 4R |
| 34 10F 70 3D 106 5P 35 11E 71 3C 107 5N | | | | | 105 | 4P |
| 35 11E 71 3C 107 5N | | - | | | 106 | 5P |
| | | | | | 107 | 5N |
| | 36 | 10E | 72 | 1D | 108 | 5R |

Note: 1. NC pins are read as "X" (i.e. don't care.)





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Internal

1Mx36 & 2Mx18 QDR[™] II+ b4 SRAM

JTAG DC OPERATING CONDITIONS

| Parameter | Symbol | Min | Тур | Max | Unit | Note |
|-------------------------------|--------|------|-----|---------|------|------|
| Power Supply Voltage | Vdd | 1.7 | 1.8 | 1.9 | V | |
| Input High Level | Vін | 1.3 | - | VDD+0.3 | V | |
| Input Low Level | VIL | -0.3 | - | 0.5 | V | |
| Output High Voltage(Iон=-2mA) | Vон | 1.4 | - | Vdd | V | |
| Output Low Voltage(IoL=2mA) | Vol | Vss | - | 0.4 | V | |

Note: 1. The input level of SRAM pin is to follow the SRAM DC specification.

JTAG AC TEST CONDITIONS

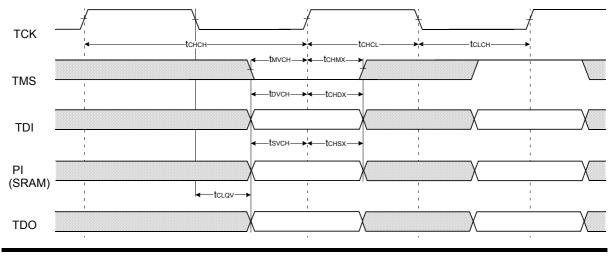
| Parameter | Symbol | Min | Unit | Note |
|---|---------|---------|------|------|
| Input High/Low Level | VIH/VIL | 1.8/0.0 | V | |
| Input Rise/Fall Time | TR/TF | 1.0/1.0 | ns | |
| Input and Output Timing Reference Level | | 0.9 | V | 1 |

Note: 1. See SRAM AC test output load.

JTAG AC Characteristics

| Parameter | Symbol | Min | Мах | Unit | Note |
|---------------------------|--------|-----|-----|------|------|
| TCK Cycle Time | tснсн | 50 | - | ns | |
| TCK High Pulse Width | tCHCL | 20 | - | ns | |
| TCK Low Pulse Width | tclch | 20 | - | ns | |
| TMS Input Setup Time | tмvсн | 5 | - | ns | |
| TMS Input Hold Time | tснмх | 5 | - | ns | |
| TDI Input Setup Time | tdvcн | 5 | - | ns | |
| TDI Input Hold Time | tCHDX | 5 | - | ns | |
| SRAM Input Setup Time | tsvcн | 5 | - | ns | |
| SRAM Input Hold Time | tchsx | 5 | - | ns | |
| Clock Low to Output Valid | tcLQV | 0 | 10 | ns | |

JTAG TIMING DIAGRAM

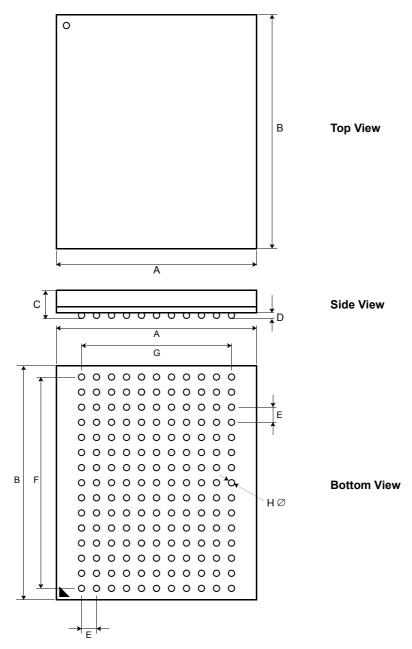


SAMSUNG ELECTRONICS Rev. 1.3 August 2008

1Mx36 & 2Mx18 QDR[™] II+ b4 SRAM

165 FBGA PACKAGE DIMENSIONS

15mm x 17mm Body, 1.0mm Bump Pitch, 11x15 Ball Array



| Symbol | Value | Units | Note | Symbol | Value | Units | Note |
|--------|---------------|-------|------|--------|--------------|-------|------|
| A | 15 ± 0.1 | mm | | E | 1.0 | mm | |
| В | 17 ± 0.1 | mm | | F | 14.0 | mm | |
| С | 1.3 ± 0.1 | mm | | G | 10.0 | mm | |
| D | 0.35 ± 0.05 | mm | | н | 0.5 ± 0.05 | mm | |



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